

# FFSH15120ADN\_F155 Silicon Carbide Schottky Diode 1200 V, 15 A

### Features

- Max Junction Temperature 175 °C
- Avalanche Rated 80 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery

## Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

FFSH15120ADN\_F155 — Silicon Carbide Schottky Diode

# Description

SiC Schottky Diode has no switching loss, provides improved system efficiency against Si diodes by utilizing new semiconductor material - Silicon Carbide, enables higher operating frequency, and helps increasing power density and reduction of system size/cost. Its high reliability ensures robust operation during surge or over-voltage conditions



## Absolute Maximum Ratings T<sub>C</sub> = 25 °C unless otherwise noted. (per leg)

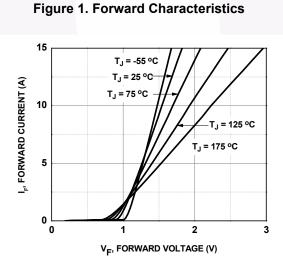
Symbol	Parameter	FFSH15120ADN_F155	Unit	
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage	1200	V	
E <sub>AS</sub>	Single Pulse Avalanche Energy	80	mJ	
lF	Continuous Rectified Forward Current @ Tc ·	8* / 15**	А	
	Non-Repetitive Peak Forward Surge Cur-	T <sub>C</sub> = 25 °C, 10 μs	560	А
IF, Max	rent	T <sub>C</sub> = 150 °C, 10 μs	500	А
I <sub>F,SM</sub>	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	80	А
I <sub>F,RM</sub>	Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	36	А
Dtat	Deurez Dissingtion	T <sub>C</sub> = 25 °C	110	W
Ptot	Power Dissipation	T <sub>C</sub> = 150 °C	19	W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-55 to +175	°C	
	TO247 Mounting Torque, M3 Screw	60	Ncm	
Thermal Ch	aracteristic			
Symbol	Parameter	FFSH15120ADN_F155	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max	1.35* / 0.56**	°C/W	

\* Per leg, \*\* Per Device

Part N	umber	Top Mark		Package	Pack	ing Method	Reel S	Size	Tape Width	Qua	antity
FFSH15120ADN_F155 FFSH15120ADN T		TO-	TO-247 Long Lead Tube		N/A		N/A	30	30 units		
Electric	al Chara	cteristics T <sub>C</sub>	= 25 °	°C unless otherv	vise no	oted. (per leg)					
Symbol		Parameter			Tes	t Conditions		Min	. Тур.	Max.	Unit
V <sub>F</sub> Forwar				I <sub>F</sub> = 8 /	ч, т <sub>с</sub> =	= 25 °C		-	1.45	1.75	1
	Forward Vo	oltage		I <sub>F</sub> = 8 /	А, Т <sub>С</sub> =	= 125 °C		-	1.7	2	V
				I <sub>F</sub> = 8 /	А, Т <sub>С</sub> =	= 175 °C		-	2	2.4	
I <sub>R</sub> Reve				V <sub>R</sub> = 1	200 V,	T <sub>C</sub> = 25 °C		-	-	200	
	Reverse C	Reverse Current		V <sub>R</sub> = 1	200 V,	T <sub>C</sub> = 125 °C		-	-	300	μA
				V <sub>R</sub> = 1	200 V,	T <sub>C</sub> = 175 <sup>o</sup> C		-	-	400	
Q <sub>C</sub>	Total Capa	citive Charge		V = 80	0 V 0			-	55	-	nC
С				V <sub>R</sub> = 1	V, f =	100 kHz		-	538	-	
	Total Capa	Total Capacitance		V <sub>R</sub> = 4	00 V, <sup>.</sup>	f = 100 kHz		-	50	-	pF
				V <sub>R</sub> = 8	00 V, <sup>.</sup>	f = 100 kHz		-	40	-	1

Notes: 1: EAS of 80 mJ is based on starting T<sub>J</sub> = 25 °C, L = 0.5 mH, I<sub>AS</sub> = 18 A, V = 150 V.

# Typical Characteristics T<sub>J</sub> = 25 °C unless otherwise noted (per leg).



**Figure 3. Reverse Characteristics** 

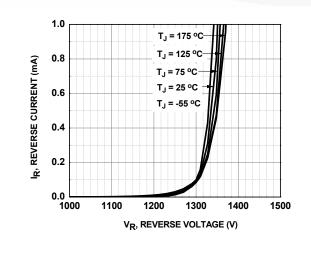
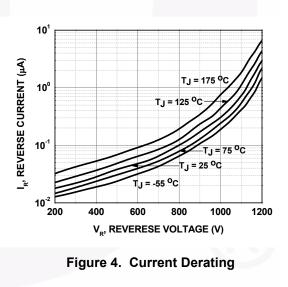
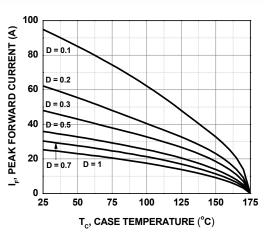
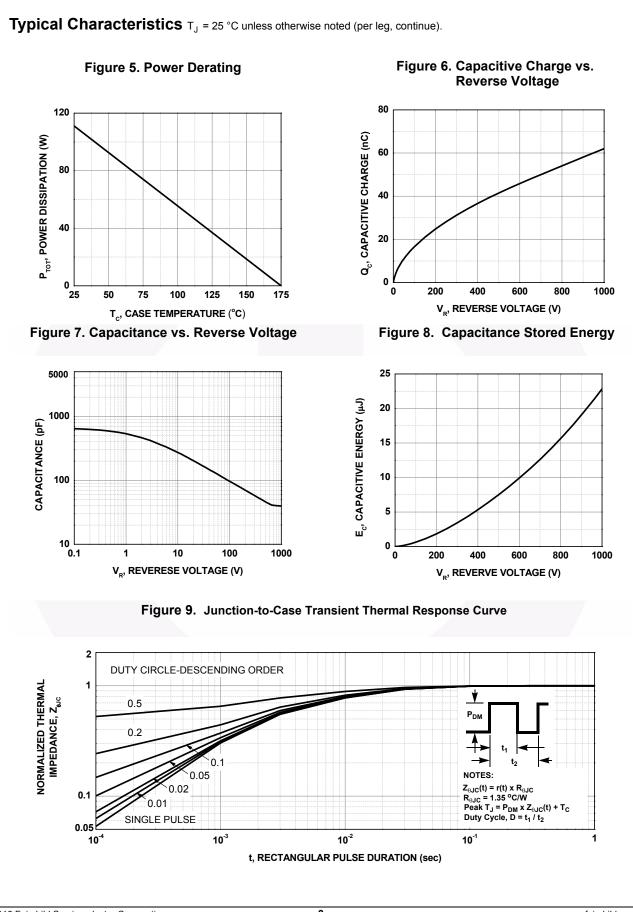
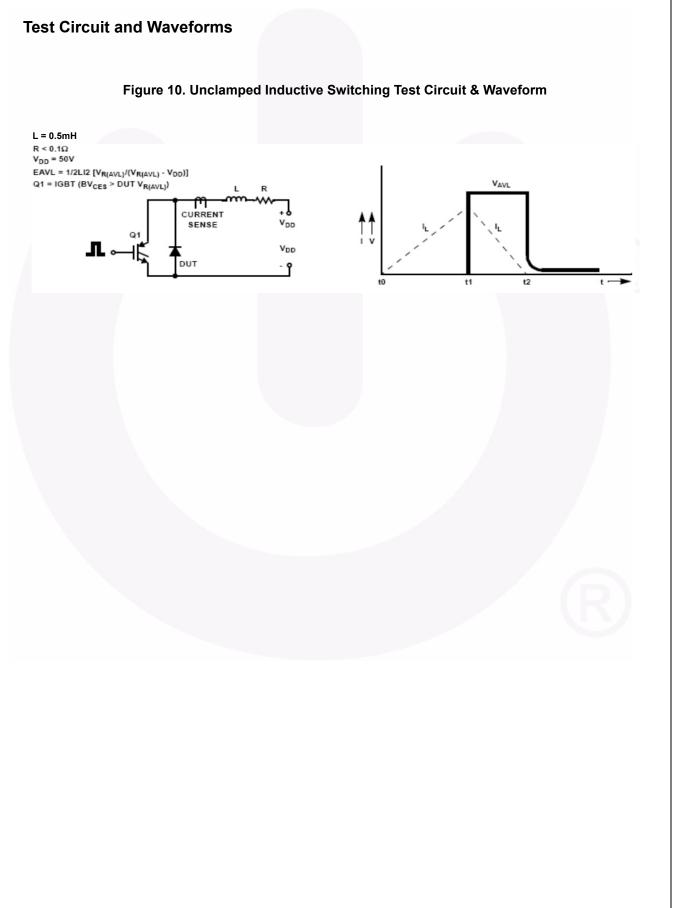


Figure 2. Reverse Characteristics

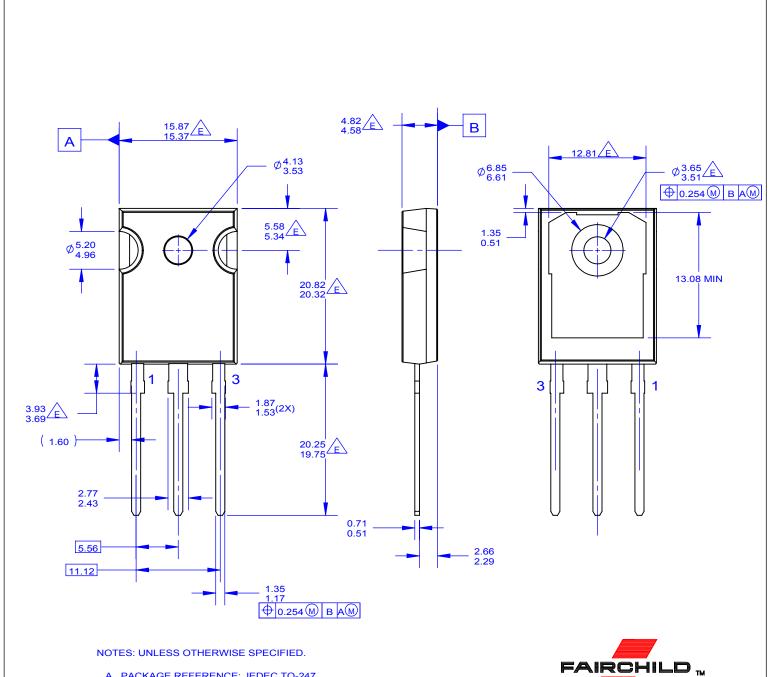








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